

SANYO Semiconductors DATA SHEET

2SK3618— General-Purpose Switching Device Applications

Features

- · Low ON-resistance.
- · Ultrahigh-speed switching.
- 4V drive.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		100	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	ID		8	А
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	32	А
Allowable Power Dissipation	PD		1	W
	""	Tc=25°C	20	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			l loit
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	I _D =1mA, V _G S=0V	100			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =100V, V _{GS} =0V			1	μΑ
Gate-to-Source Leakage Current	IGSS	V _{GS} =±16V, V _{DS} =0V			±10	μΑ
Gate-to-Source Cutoff Voltage	VGS(off)	V _{DS} =10V, I _D =1mA	1.2		2.6	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =4A	4	7		S
Static Drain-to-Source On-State Resistance	R _{DS} (on)1	I _D =4A, V _G S=10V		100	130	mΩ
	RDS(on)2	ID=4A, VGS=4V		130	180	mΩ
Input Capacitance	Ciss	V _{DS} =20V, f=1MHz		880		pF
Output Capacitance	Coss	V _{DS} =20V, f=1MHz		80		pF
Reverse Transfer Capacitance	Crss	V _{DS} =20V, f=1MHz		55		pF
Turn-ON Delay Time	t _d (on)	See specified Test Circuit.		11.5		ns
Rise Time	t _r	See specified Test Circuit.		14		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		100		ns
Fall Time	tf	See specified Test Circuit.		42		ns

Marking: K3618 Continued on next page.

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2SK3618

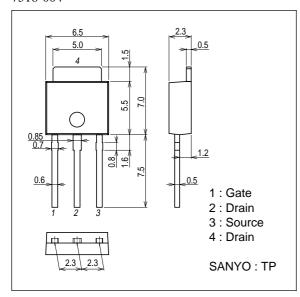
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Total Gate Charge	Qg	V _{DS} =50V, V _{GS} =10V, I _D =8A		24		nC
Gate-to-Source Charge	Qgs	V _{DS} =50V, V _{GS} =10V, I _D =8A		3.2		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =50V, V _{GS} =10V, I _D =8A		5.5		nC
Diode Forward Voltage	VSD	IS=8A, VGS=0V		0.9	1.2	V

Note) Although the protection diode is contained between gate and source, be careful of handling enough.

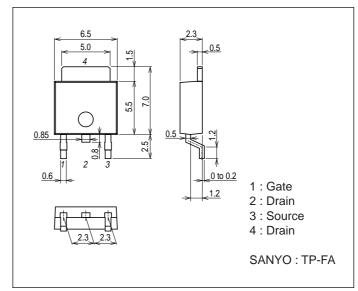
Package Dimensions

unit : mm 7518-004

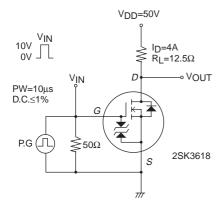


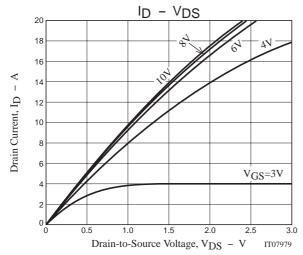
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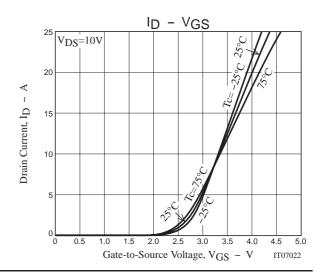
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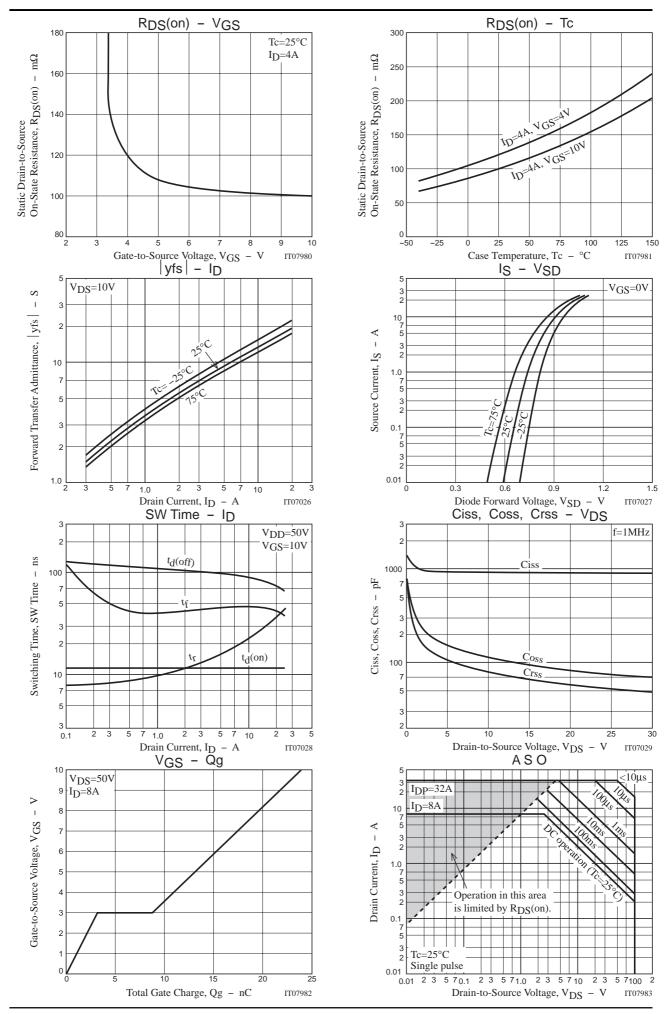


Switching Time Test Circuit

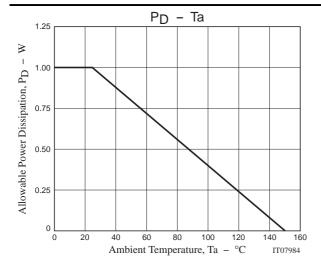


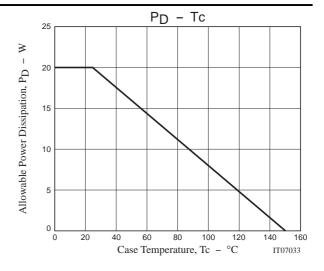






2SK3618





Note on usage: Since the 2SK3618 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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